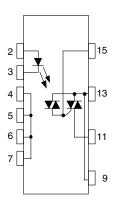


Vishay Semiconductors

Power Phototriac

Function 2 LED anode 3 LED cathode 4 N/C 5 N/C 6 N/C N/C 7 9, 13 Triac T2 Triac T1 15 Triac gate



21081

DESCRIPTION

The VO3526 is an optically couple phototriac driving a power triac in a DIP-10 (16) package. It provides a 5300 V of input to output isolation.

FEATURES

- Maximum trigger current (IFT): 10 mA
- Isolation test voltage 5300 V_{RMS}
- Peak off-state voltage 600 V
- Load current 1 A
- dV/dt of 500 V/μs
- · Pure tin leads

e3 RoHS

APPLICATIONS

- Triac driver
- · Programable controllers
- · AC-output module

AGENCY APPROVALS

- UL E52744 system code H
- CUL E52744 system code H
- VDE DIN EN 60747-5-5 (VDE 0884)

ORDER INFORMATION	
PART	REMARKS
VO3526	Tubes, DIP-10 (16)

Note

For additional information on the possible lead bend and VDE options refer to option information.

ABSOLUTE MAXIMUM RATINGS (1)							
PARAMETER	TEST CONDITION	TEST CONDITION SYMBOL		UNIT			
INPUT							
LED continuous forward current		I _F	50	mA			
LED reverse voltage		V _R	5.0	V			
OUTPUT							
Repetitive peak off-state voltage	Sine wave, 50 to 60 Hz, gate open	V _{DRM} 600		V			
On-state RMS current		I _{T(RMS)}	1.0	Α			
Peak nonrepetitive surge current (50 Hz, peak)		I _{TSM}	10	Α			
COUPLER							
Total power dissipation		P _{diss}	1.2	W			
Ambient temperature range		T _{amb}	- 40 to + 85	°C			
Storage temperature range		T _{stg}	- 40 to + 125	°C			
Soldering temperature (2)	t ≤ 10 s max.	T _{sld}	260	°C			
Isolation test voltage	for 1.0 s	V _{ISO}	5300	V _{RMS}			

Notes

- (1) T_{amb} = 25 °C, unless otherwise specified.
 - Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (2) Refer to wave profile for soldering conditions for through hole devices.
- (3) Total power dissipation value is based on 2S2P PCB. Refer to power phototriac application note for PCB design tips.



ABSOLUTE MAXIMUM RATING CURVES

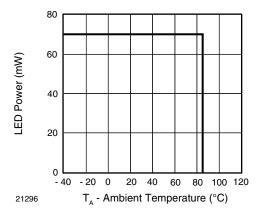


Fig. 1 - Power Dissipation vs. Temperature

THERMAL CHARACTERISTICS						
PARAMETER	SYMBOL	VALUE	UNIT			
Maximum LED junction temperature	T _{jmax.}	105	°C			
Maximum NOT junction temperature	T _{jmax.}	105	°C			
Thermal resistance, junction NOT to bord	θ_{NOT-B}	75	°C/W			
Thermal resistance, junction NOT to case	θ _{NOT-C}	150	°C/W			
Thermal resistance, junction OT to board	θот-в	158	°C/W			
Thermal resistance, junction OT to case	θот-с	157	°C/W			
Thermal resistance, junction emitter to board	θ_{E-B}	149	°C/W			
Thermal resistance, junction emitter to case	$\theta_{\text{E-C}}$	161	°C/W			
Thermal resistance, junction NOT to junction OT	θ_{NOT-OT}	243	°C/W			
Thermal resistance, junction emitter to junction NOT	$\theta_{\text{E-NOT}}$	420	°C/W			
Thermal resistance, junction emitter to junction OT	$\theta_{\text{E-OT}}$	235	°C/W			
Thermal resistance, case to ambient	$\theta_{\sf CA}$	130	°C/W			

Note

The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's Thermal Characteristics of Power Phototriac application note.

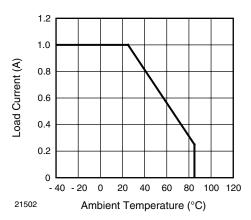
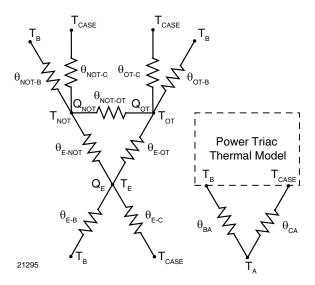


Fig. 2 - Allowable Load Current vs. Ambient Temperature

Note

The allowable load current was calculated out under a given operating conditions and only for reference:

LED power: $Q_E = 0.015 \text{ W}$, θ_{BA} (4-layer) = 30 °C/W



Thermal Model

NOT: Non-opto-triac OT: Opto-triac

T_B: Board temperatureT_{CASE}: Case temperatureT_A: Ambient temperature

 θ_{BA} : Thermal resistance, board to ambient

 $\begin{array}{ll} Q_E \colon & \text{LED power dissipation} \\ Q_{OT} \colon & \text{OT power dissipation} \\ Q_{NOT} \colon & \text{NOT power dissipation} \end{array}$



Vishay Semiconductors

ELECTRICAL CHARACTERISTICS									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT									
LED trigger current	$V_T = 6 V$	I _{FT}			10	mA			
Input reverse current	V _R = 5 V	I _R			10	μΑ			
LED forward voltage	I _F = 10 mA	V _F	0.9		1.4	V			
OUTPUT									
Peak on-state voltage	I _{TM} = 1.5 A	V _{TM}			1.7	V			
Repetitive peak off-state current	$V_{DRM} = 600 \text{ V},$ $T_A = 110 ^{\circ}\text{C}, 60 \text{ Hz}$	I _{DRM}			100	μΑ			
Holding current	$R_L = 100 \Omega$	I _H			25	mA			
Critical rate of rise of off-state voltage	V _{IN} = 400 V (fig. 3)	dV/dt		210		V/µs			
Critical rate of rise of commutating voltage	$V_{IN} = 240 V_{RMS},$ $I_T = 1 A_{RMS}$ (fig. 3)	dV/dt (c)		0.9		V/µs			

Note

 T_{amb} = 25 °C, unless otherwise specified. Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

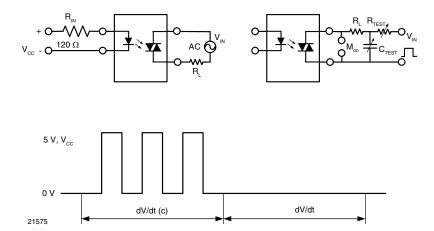


Fig. 3 - dV/dt Test Circuit

RECOMMENDED OPERATING CONDITIONS								
PARAMETER			TEST CONDITION	SYMBOL	MIN.	MAX.	UNIT	
Forward current at on-state		Input		I _{F(ON)}	10	20	mA	
Forward current at off-state		iriput		I _{F(OFF)}	0	0.1	mA	
Load supply voltage	_		With snubber (0.022 μ F, 47 Ω)	V _{OUT(RMS)}		240	V	
On-state RMS current	T _A = 40 °C	Output	On 4-layer PCB (R _{BA} = 30 °C/W) I _{OUT(RMS)}		0.8	Α		
On-state RMS current	T _A = 60 °C			OUT(RMS)		0.6	Α	
Frequency				f	50	60	Hz	
Operating temperature					- 40	85	°C	



PARAMETER	UN KAIINGS	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
			SYMBOL	WIIN.		WAX.	UNII
Climatic classification		IEC 68 part 1			40/85/21		
Pollution degree		DIN VDE 0109			2		
Tracking resistance (comparative tra	cking index)	Insulation group IIIa	CTI	175			
Highest allowable overvoltage		Transient overvoltage	V _{IOTM}	8000			V_{peak}
Maximum working insulation voltage		Recurring peak voltage	V _{IORM}	890			V _{peak}
Insulation resistance at 25 °C		V _{IO} = 500 V	R _{IS}			≥ 10 ¹²	Ω
Insulation resistance at T _S		V _{IO} = 500 V	R _{IS}			≥ 10 ⁹	Ω
Insulation resistance at 100 °C		V _{IO} = 500 V	R _{IS}			≥ 10 ¹¹	Ω
Partial discharge test voltage		Method b, V _{pd} = V _{IORM} x 1.6	V_{pd}			1424	V _{peak}
Safety limiting values -	Output power		P _{SO}			2	W
maximum values allowed in the	Input current		I _{SI}			150	mA
event of a failure	Case temperature		T _{SI}			165	°C
Minimum external air gap (clearance)		Measured from input terminals to output terminals, shortest distance through air		≥ 7			mm
Minimum external tracking (creepage)		Measured from input terminals to output terminals, shortest distance path along body		≥7			mm

Note

This phototriac coupler is suitable for 'safe electrical insulation' only within the safety ratings. Compliance with safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

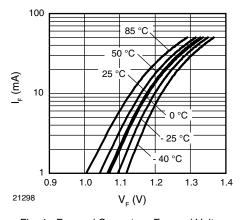


Fig. 4 - Forward Current vs. Forward Voltage

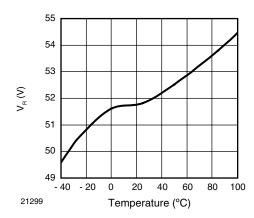


Fig. 5 - Diode Reverse Voltage vs. Temperature



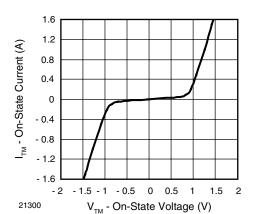


Fig. 6 - On-State Current vs. On State Voltage

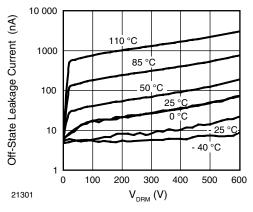


Fig. 7 - Off-State Leakage Current vs. Voltage

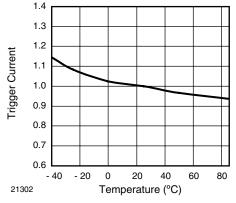


Fig. 8 - Normalized Trigger Input Current vs. Temperature

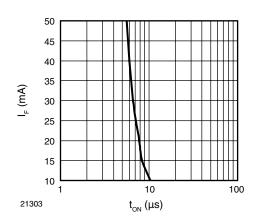


Fig. 9 - Trigger Input Current vs. Turn-on Time

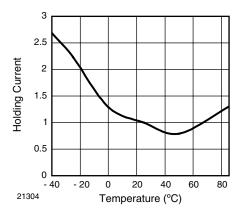


Fig. 10 - Normalized Holding Current vs. Temperature

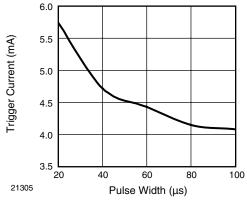


Fig. 11 - Trigger Current vs. Trigger Pulse Width



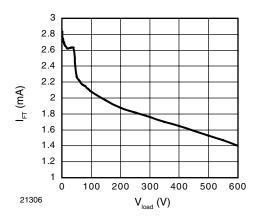
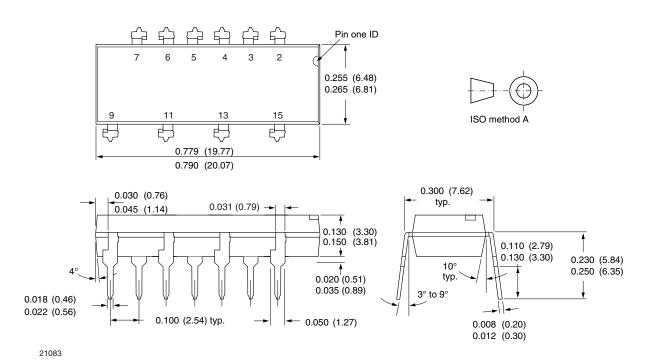


Fig. 12 - Trigger Current vs. V_{load}

PACKAGE DIMENSIONS in inches (millimeters)





Vishay Semiconductors

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com